

BC212B

PNP General Purpose Amplifier

- This device is designed for general purpose amplifier application at collector currents to 100mA.
- Sourced from process 68.



1. Collector 2. Base 3. Emitter

Absolute Maximum Ratings* T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	50	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current - Continuous	100	mA
T _{J,} T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1. These ratings are based on a maximum junction temperature of 150°C.

 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_C=25°C unless otherwise noted

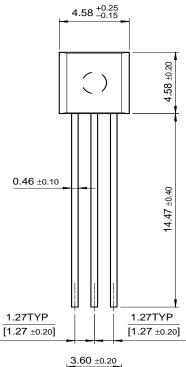
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	Off Characteristics					
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 2mA$	50			V
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 10\mu A$	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 10μA	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = 30V			15	nA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 4V			15	nA
On Chara	On Characteristics*					
h _{FE}	DC Current Gain	$V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 2mA$	40 60			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$			0.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$			1.4	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5V, I_C = 2mA$	0.6		0.72	V
Small Signal Characteristics						
C _{ob}	Output Capacitance	V _{CE} = 10V, f = 1MHz			6	pF
h _{fe}	Small Signal Current Gain	$V_{CE} = 5V$, $I_{C} = 2mA$, $f = 1KHz$	200		400	
NF	Noise Figure	$V_{CE} = 5V$, $I_{C} = 200\mu A$, $f = 1KHz$ $R_{G} = 2K\Omega$, $BW = 200Hz$			10	dB

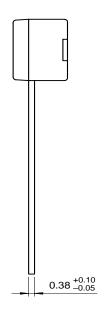
* Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

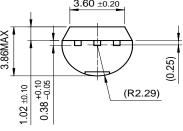
Thermal Characteristics T _A =25°C unless otherwise noted			
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient		°C/W
$R_{\theta JC}$	Thermal Resistance, Junction to Case 125		°C/W

Package Dimensions

TO-92







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